

DESCRIPTION

ML229U6-220 is a high -power, high-efficient AlGaInP semiconductor laser which provides a stable, single transverse mode oscillation with emission wavelength of 658nm and standard pulse light output of 350mW.

ML229U6-220 has a real -index-waveguide which improves the slope efficiency (reduction of the operating current) and the astigmatic distance.

FEATURES

- High Output Power: 350mW (Pulse)
- High Efficiency: 0.95W/A (typ.)
- Visible Light: 660nm (typ.)
- Low Aspect Ratio ($\theta_{\perp} / \theta_{//}$): 1.7 (typ.)
- Low Astigmatic Distance: 1 μ m (typ.)

APPLICATION

Portable High-Density Optical Disc Drives
Re-Writable DVD Drives

ABSOLUTE MAXIMUM RATINGS (Note 1)

Symbol	Parameter	Conditions	Ratings	Unit
Po	Light output power	CW	200	mW
		Pulse(Note 2)	350	
VRL	Reverse voltage	-	2	V
Tc	Case temperature	-	-10 ~ +75	°C
Tstg	Storage temperature	-	-40 ~ +100	°C

Note1: The maximum rating means the limitation over which the laser should not be operated even instant time.
This does not mean the guarantee of its lifetime. As for the reliability, please refer to the reliability report issued by Quality Assurance Section, HF & Optical Semiconductor Division, Mitsubishi Electric Corporation.

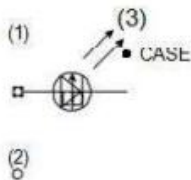
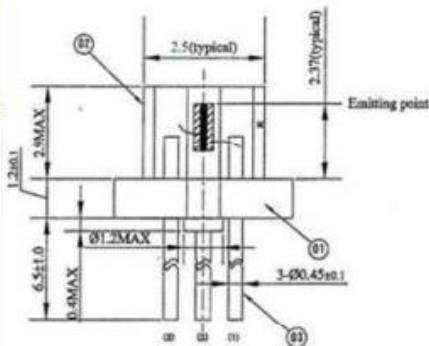
Note2: TARGET SPEC /Condition Duty Cycle: less than 35%, pulse width: less than 30ns

ELECTRICAL/OPTICAL CHARACTERISTICS (Tc=25°C)

Symbol	Parameter	Test conditions	Min.	Typ.	Max	Unit
Ith	Threshold current	CW	-	80	-	mA
Iop	Operating current	CW, Po=180mW	-	280	-	mA
Vop	Operating voltage	CW, Po=180mW	-	2.5	3.0	V
η	Slope efficiency	CW, Po=180mW	-	0.95	-	mW/mA
λ_p	Peak wavelength	CW, Po=180mW	650	660	665	nm
$\theta_{//}$	Beam divergence angle (parallel)	CW, Po=180mW	7	10	12	°
θ_{\perp}	Beam divergence angle (perpendicular)	CW, Po=180mW	14	17	20	°

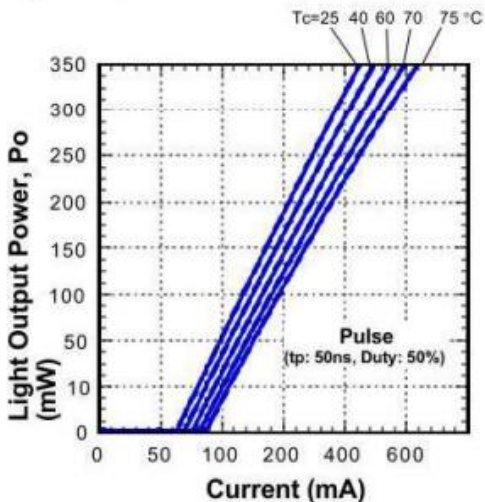
OUTLINE DRAWINGS

ML229U6-220

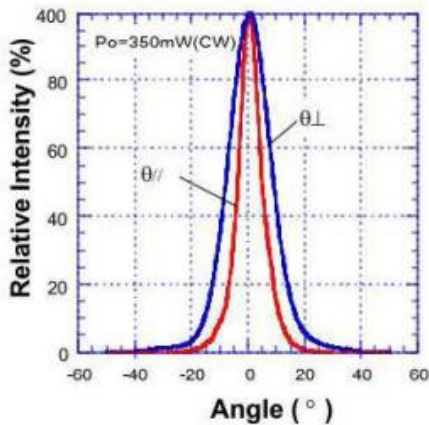


There is no model with a monitor photo diode in ML229U6-220 series.

Typical Characteristics



Light Output Power vs. Current (Pulse)



Far-Field-Patterns